



**TARTU ÜLIKOOL**  
FÜÜSIKA INSTITUUT

LUMINER



**Spectroscopic study of  
complex oxides  
solid solution  $\text{Lu}_x\text{Y}_{1-x}\text{PO}_4:\text{Ce}^{3+}$**

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## Properties of phosphates

- high thermal stability
- no phase transitions till the melting temperature ( $T_m = 2150\text{ C}$ )
- high chemical stability
- a remarkable resistance to radiation damage

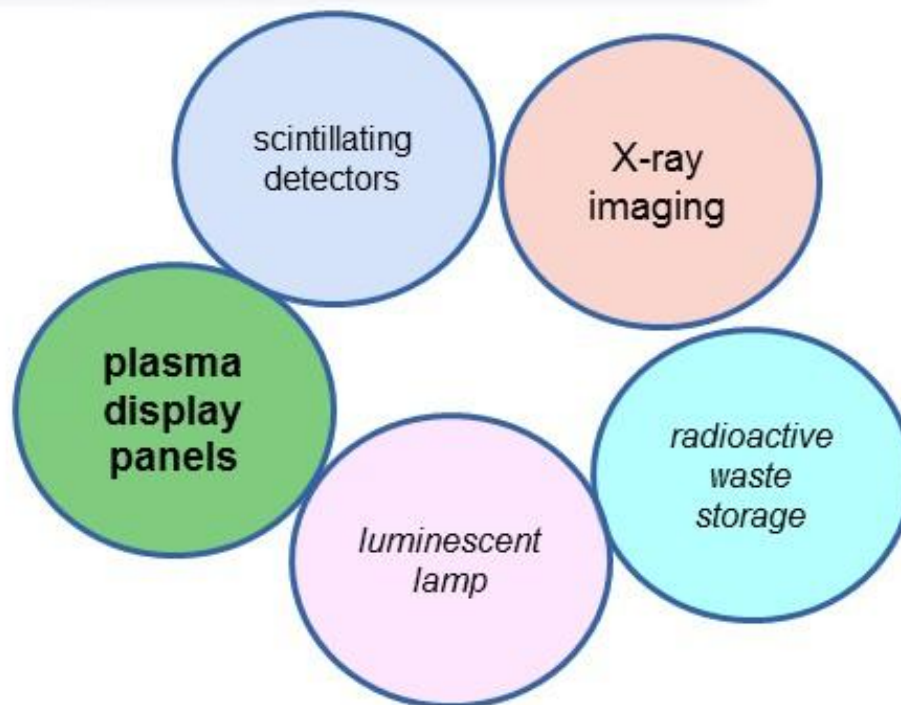
+

the luminescence properties of phosphates doped with rare-earth elements



the broad range of applications

## Potential application



## Properties of solid solution

- A solid solutions may have properties that differ from properties of its components.
- In solid solution of metals increase of resistivity has been observed. This effect is ascribed to the **clusterisation**.

Clusterisation - a local regulation of the solid solution with creation of the areas with primary content of one of the components.

## Clusterization of solid solutions

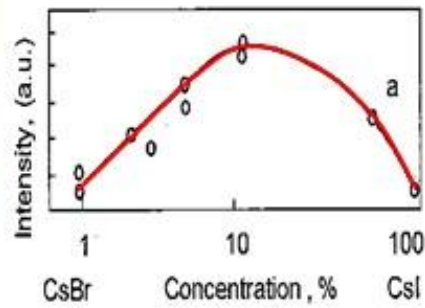
In solid solutions the clusters may appear, which **limits the thermalization length** of hot electrons and holes and therefore influences the energy transfer to the emission centers.



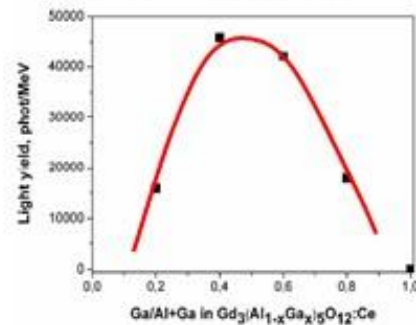
**The increase of the light yield**

# Superior light yield

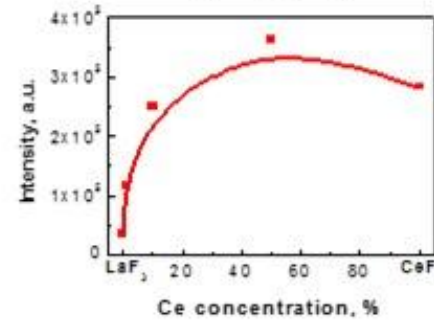
CsI-CsBr



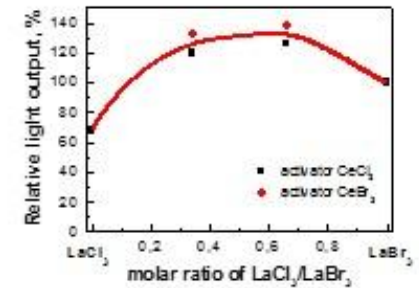
$Gd_2(Al_xGa_{1-x})_5O_{12}:Ce$



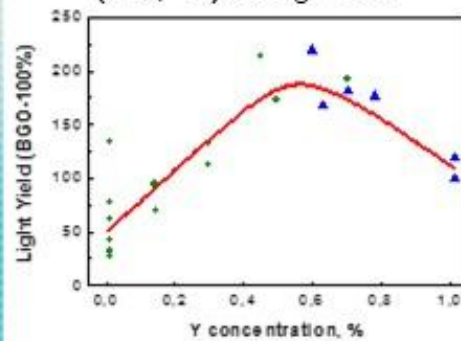
$Ce_xLa_{1-x}F_3$



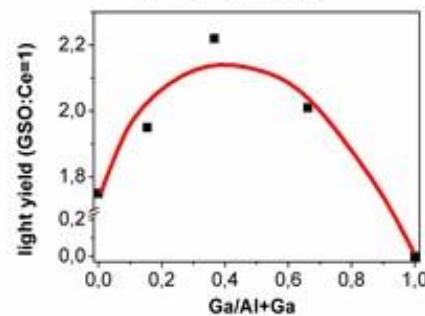
LaCl<sub>3</sub>-LaBr<sub>3</sub>



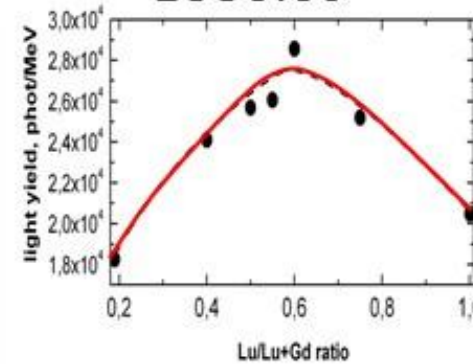
(Lu, Y)AlO<sub>3</sub>: Ce



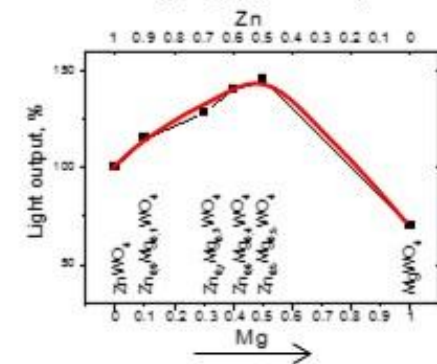
YAGG:Ce



LGSO:Ce



Zn<sub>x</sub>Mg<sub>1-x</sub>WO<sub>4</sub>



A. Belsky, A. Gektin, A. Vasil'ev, IEEE Trans.Nucl. Sci., vol.61, no.1, pp.262-270, 2014

## Aim of research

the spectroscopic investigation of a set of the  $\text{Lu}_x\text{Y}_{1-x}\text{PO}_4$  ( $x = 0, 0.1, 0.3, 0.5, 0.7, 0.9, 1$ ) phosphates solid solutions doped with 0,5 mol %  $\text{Ce}^{3+}$ .

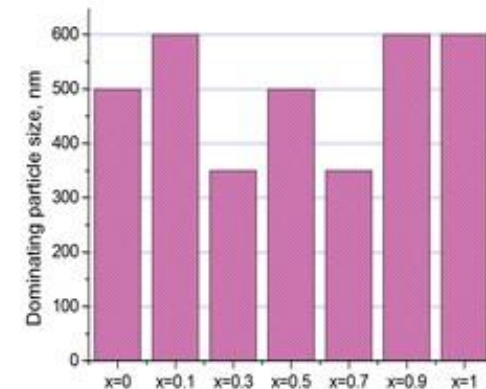
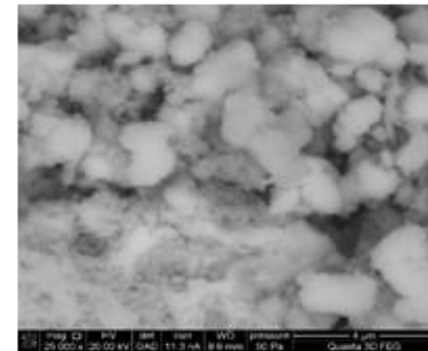
Special attention was paid to the processes of energy transfer to the emission centers in the studied compounds.

## Synthesis and crystal structure

The luminescence properties of a series of phosphate solid solutions with general formula  $\text{Lu}_x\text{Y}_{1-x}\text{PO}_4$  were studied ( $x = 0, 0.1, 0.3, 0.5, 0.7, 0.9, 1$ ) doped with 0.5 mol %  $\text{Ce}^{3+}$ .

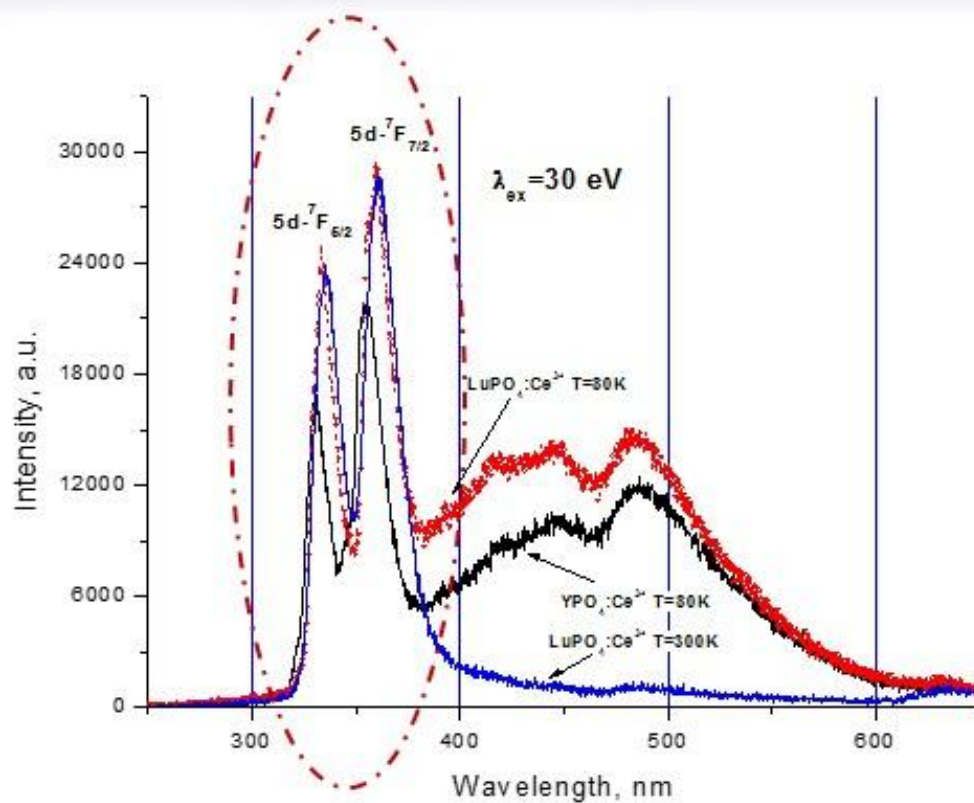
The samples were synthesized by the **sol-gel method**.

According to the data of the **grain-size analysis**, the dominating size of the particles of all compositions is around **350-600 nm**.



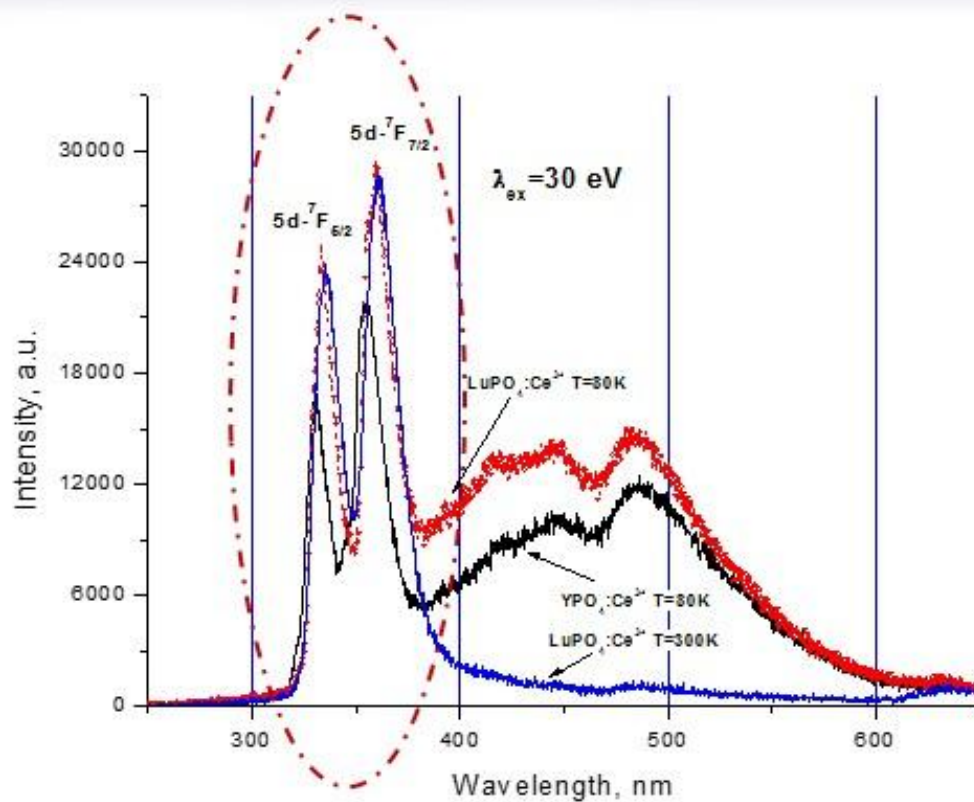


# The luminescence spectra



- the pronounced doublet peaking at 335 and 360 nm, which is connected with the 5d-4f transitions of the Ce<sup>3+</sup> ion

# The luminescence spectra



peaks shift to the longer wavelength region



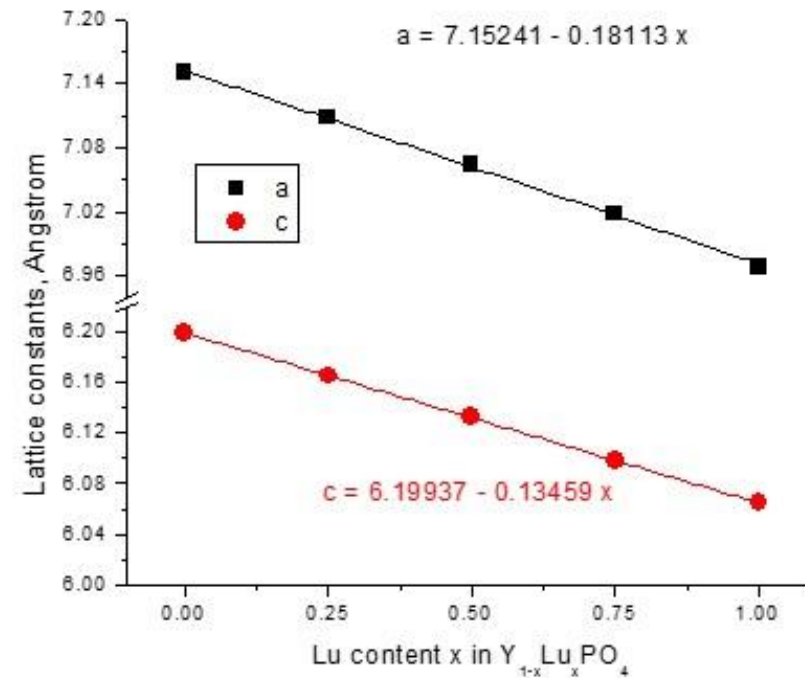
crystal field strength increases



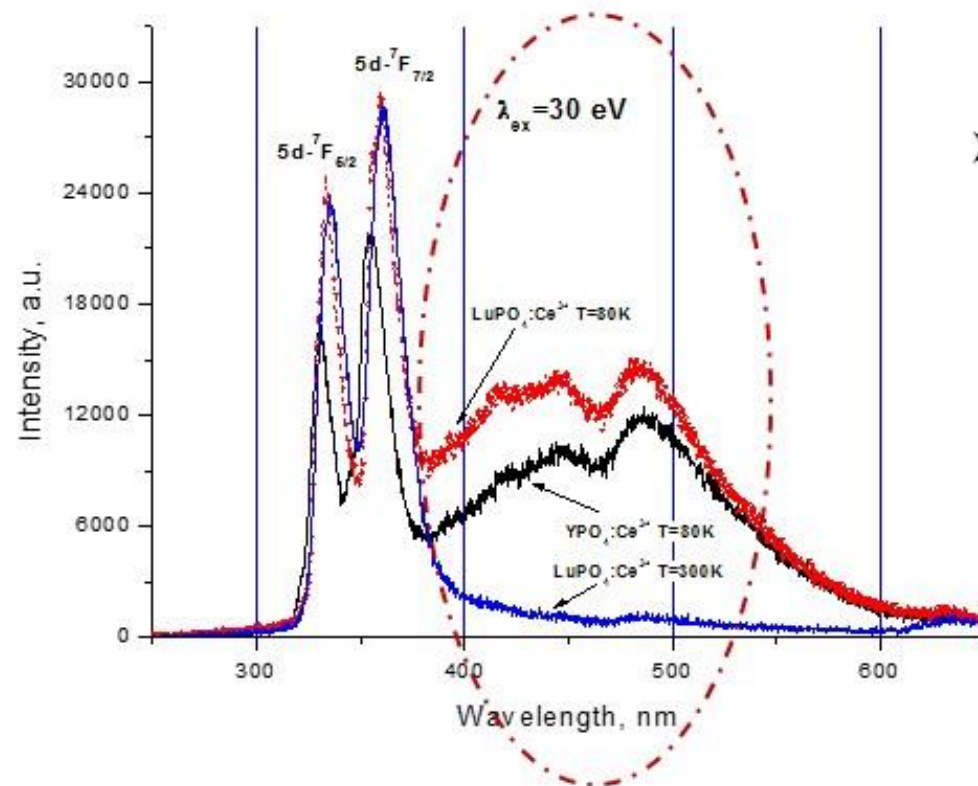
the unit cell decreases

With increase of x:

Calculated lattice constants

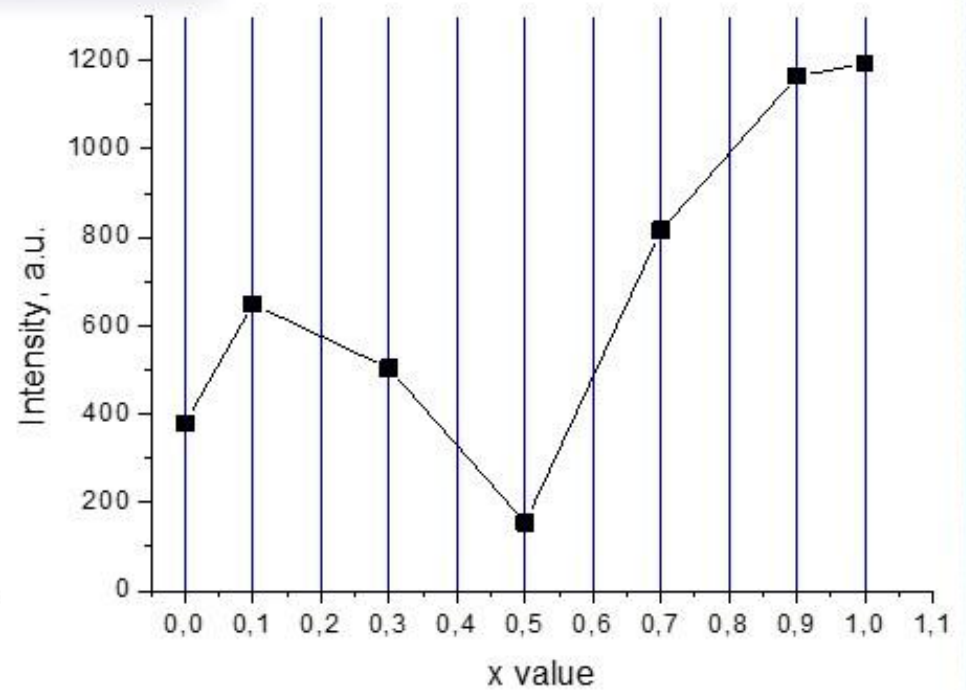
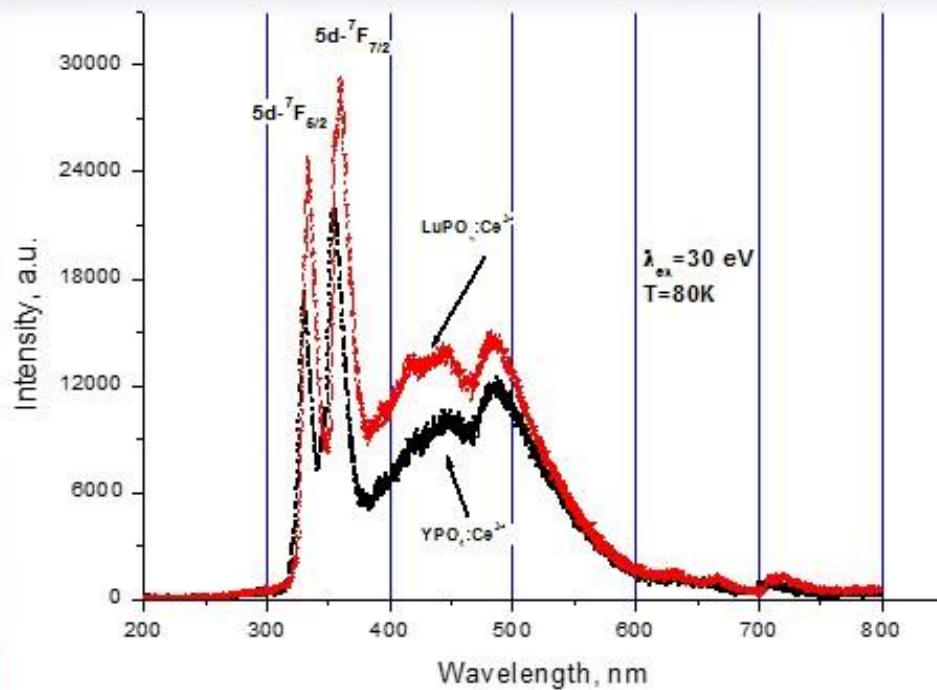


# The luminescence spectra



- at T=80K two broad bands detected in the 385 - 600 nm range, which are associated with the defect-related emission.

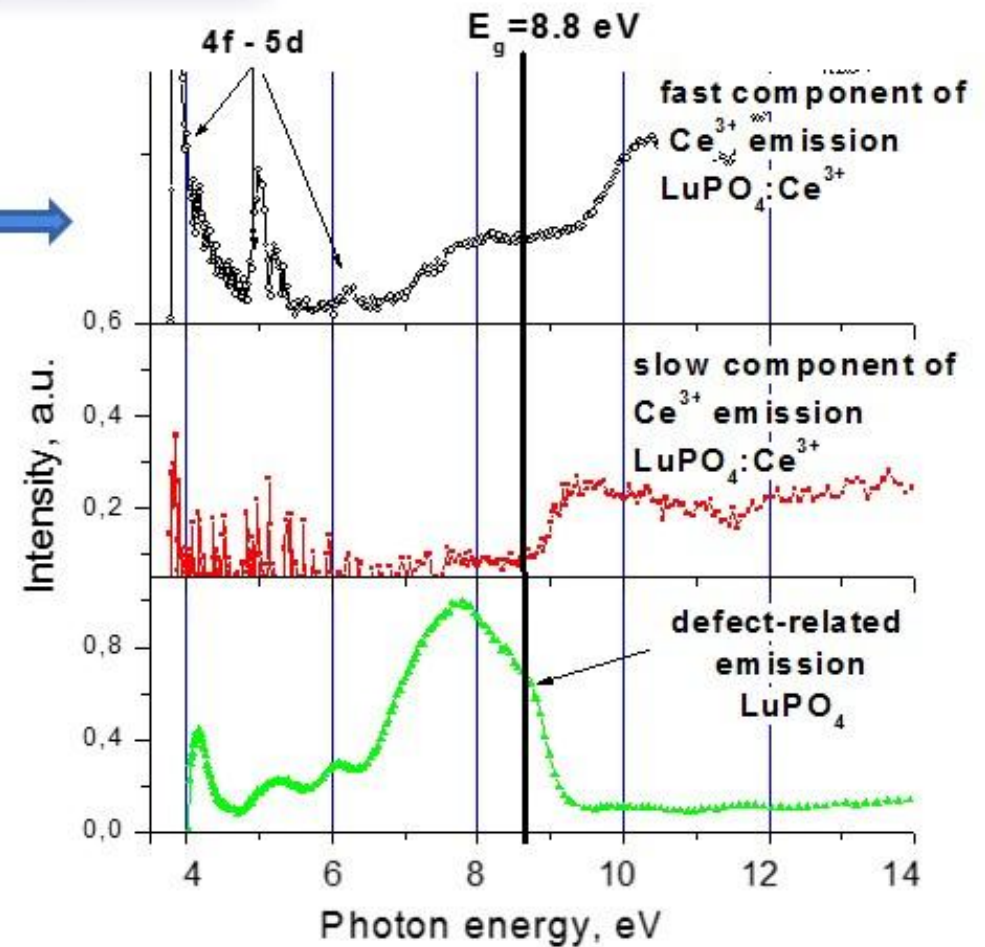
# The luminescence spectra



The decrease of the emission intensity for intermediate values of x (opposite effect to the expected one) was detected .

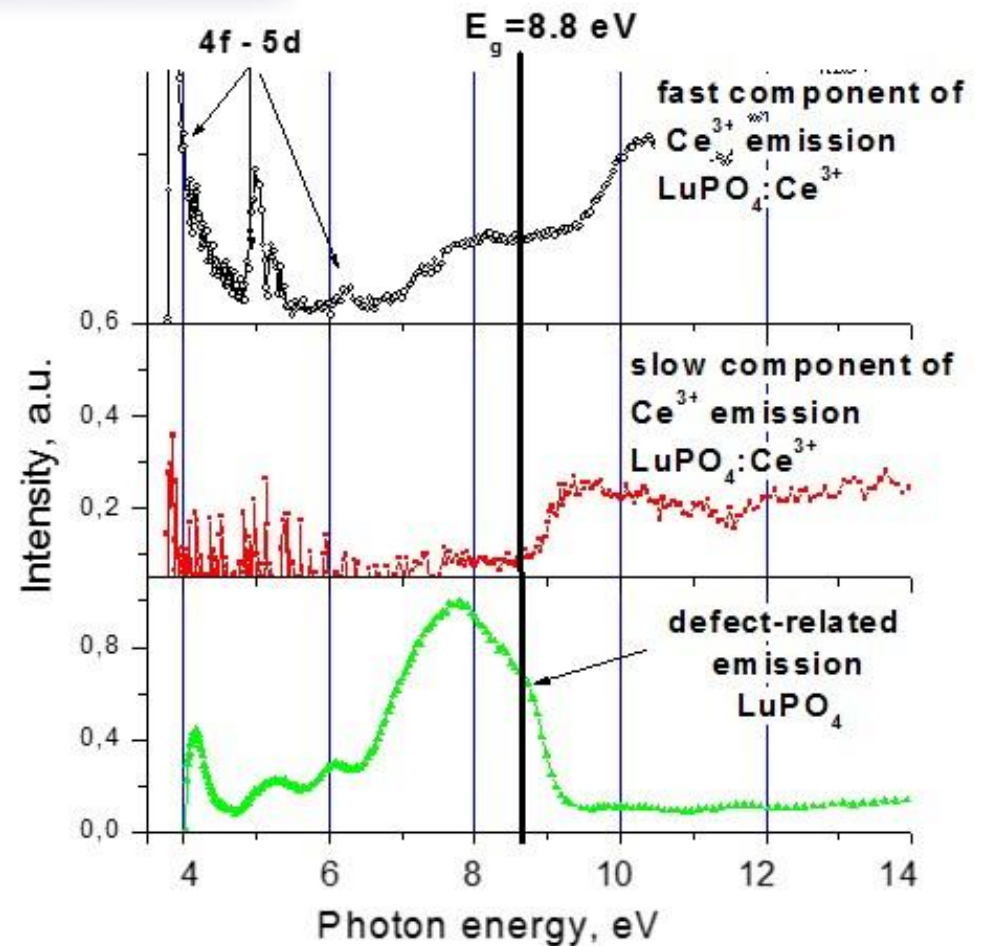
## The luminescence excitation spectra

The five bands peaking at 3.9, 4.9, 5.2, 5.5 and 6.1 eV corresponding to 4f-5d intracenter transitions in  $\text{Ce}^{3+}$  ions.



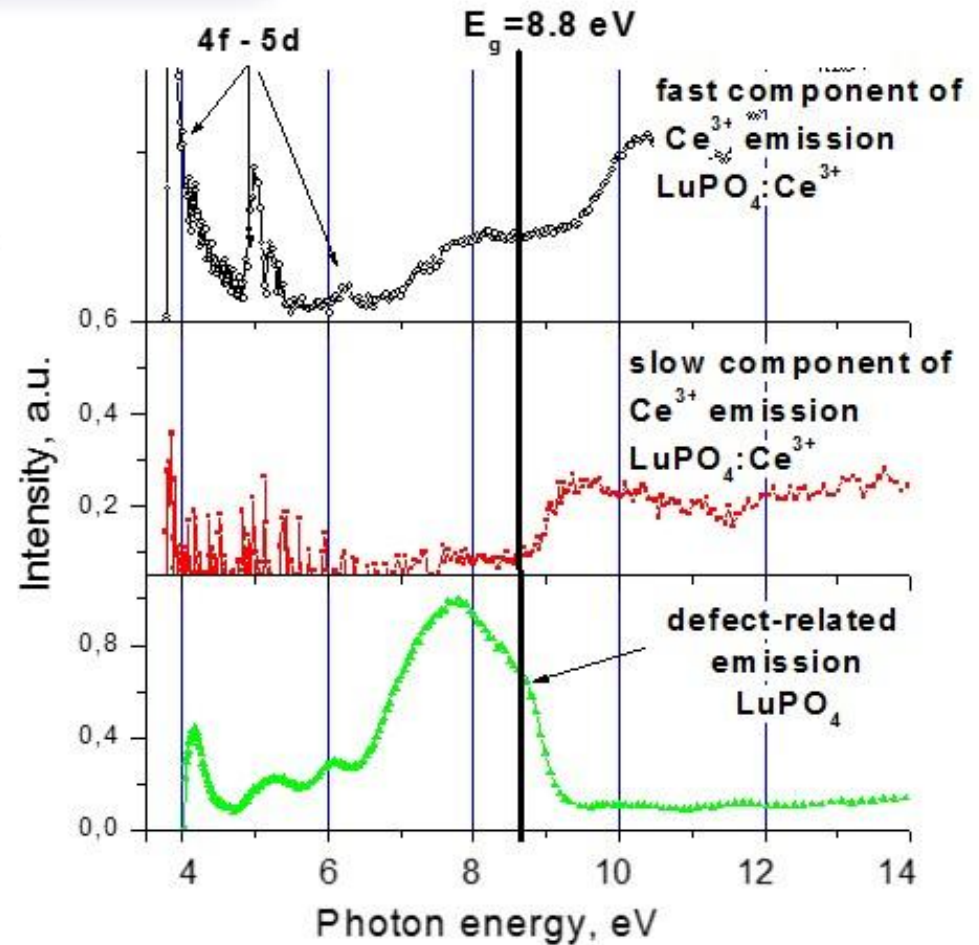
## The luminescence excitation spectra

The rise of luminescence in excitation spectrum measured in the “slow” time window starts at  $E > 8.8$  eV. The rise is connected with the creation of separated electrons and holes and can be used for the estimation of bandgap value  $E_g = 8.8$  eV.



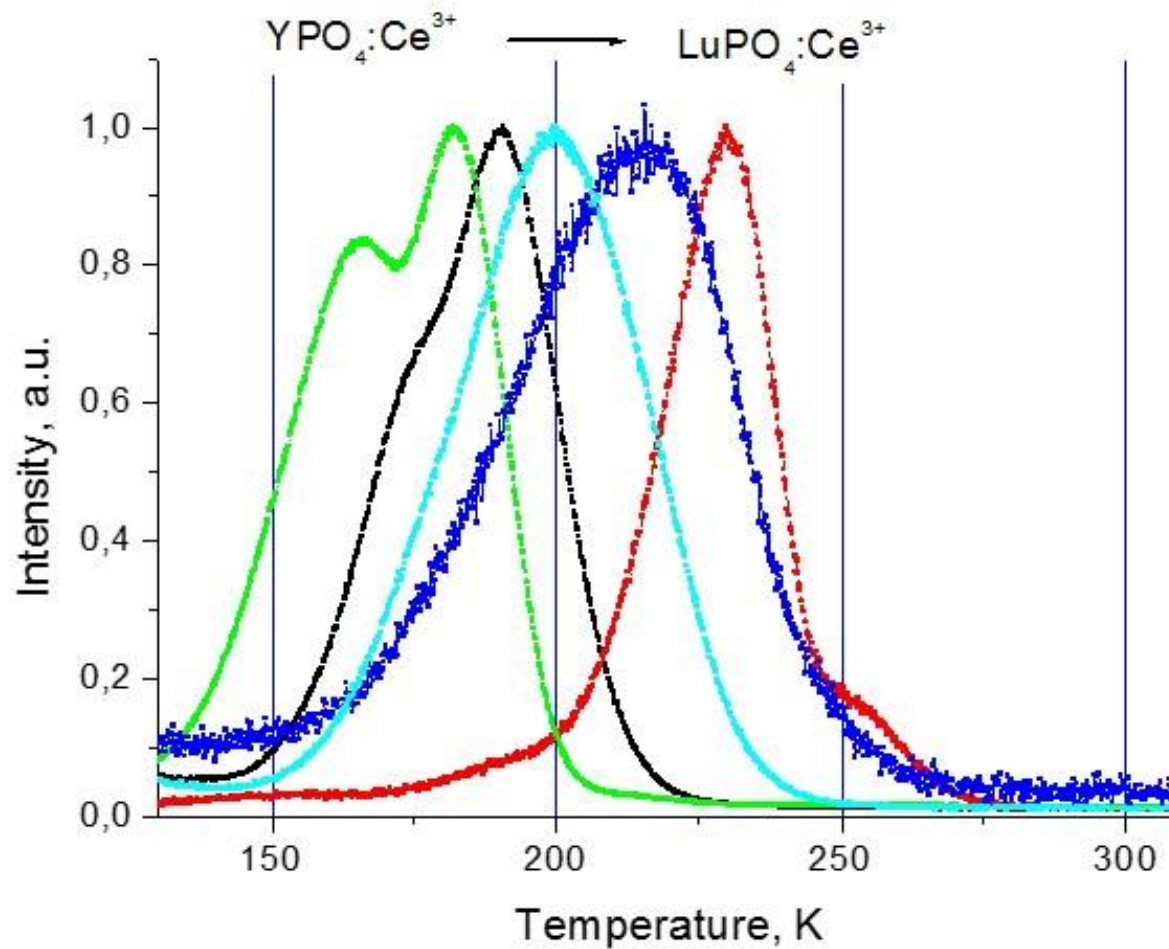
## The luminescence excitation spectra

The broad band in the region 7-9 eV is found in the "fast" component of excitation spectra of  $\text{Lu}_x\text{Y}_{1-x}\text{PO}_4:\text{Ce}^{3+}$  as well as in the excitation spectra of defect-related emission in undoped phosphates. The energy transfer from the defect states to  $\text{Ce}^{3+}$  is proposed to explain the origin of the band in the excitation spectra of  $\text{Lu}_x\text{Y}_{1-x}\text{PO}_4:\text{Ce}^{3+}$ .



# Thermally Stimulated Luminescence

With increase of  $x$ :

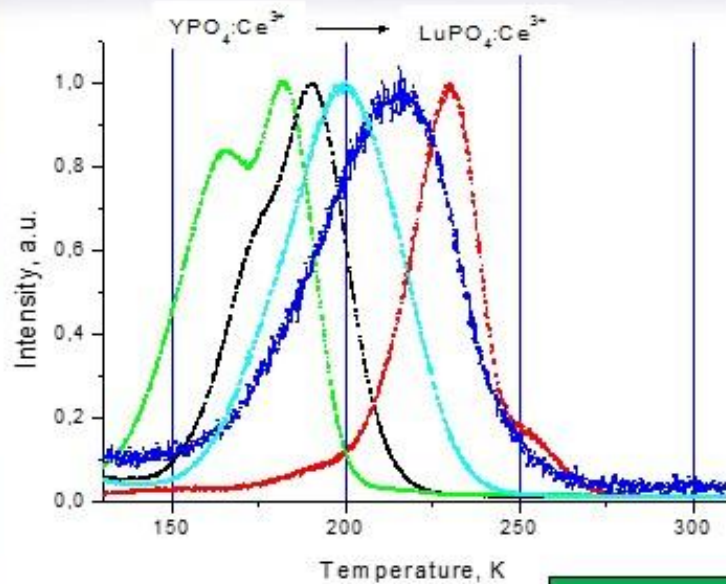


- the shift of the peak to high temperature with increase of  $x$



# Thermostimulated luminescence

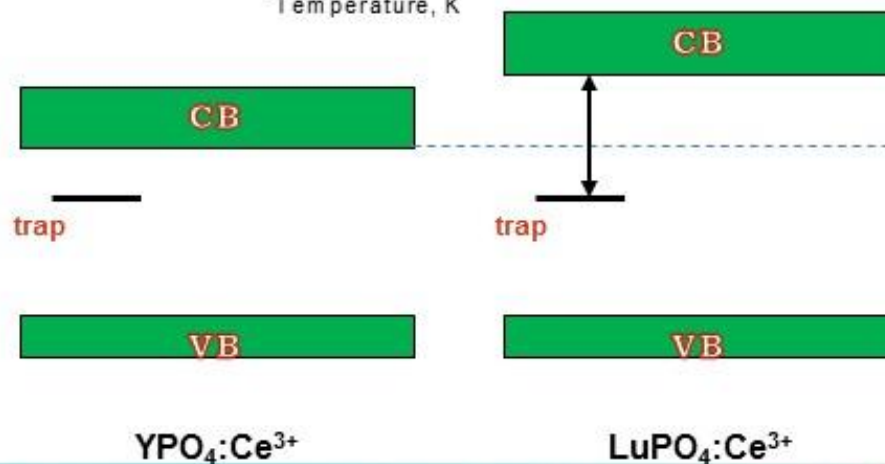
With increase of  $x$ :



- the shift of the peak to high temperature

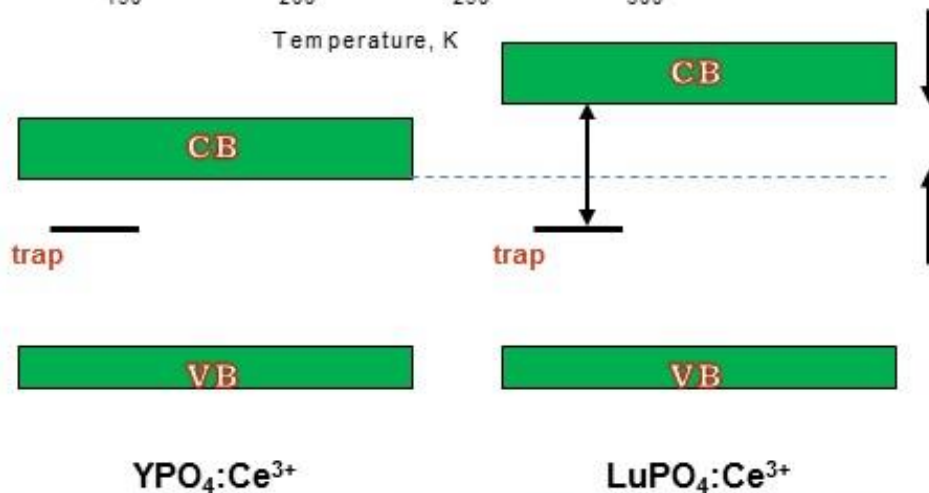
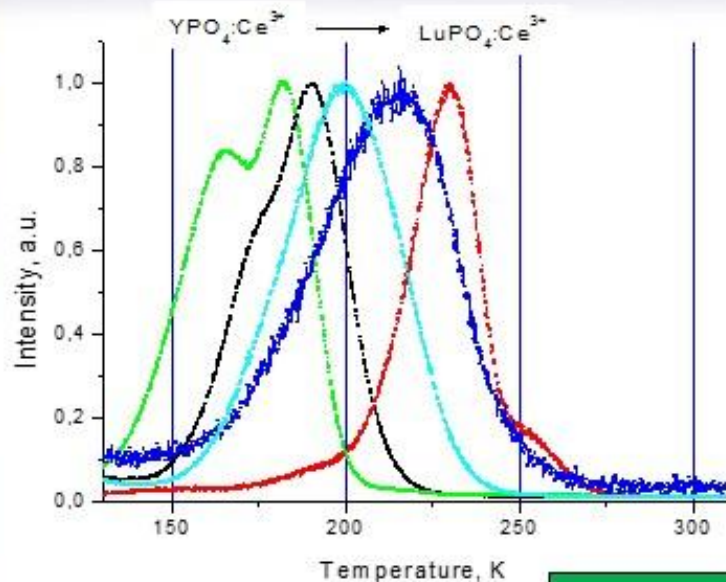


- the increase of depth of the trap



# Thermostimulated luminescence

With increase of  $x$ :



- the shift of the peak to high temperature



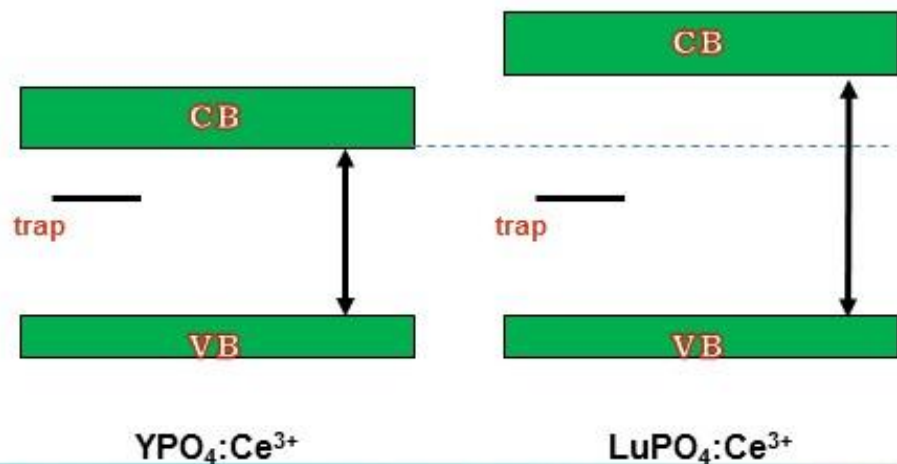
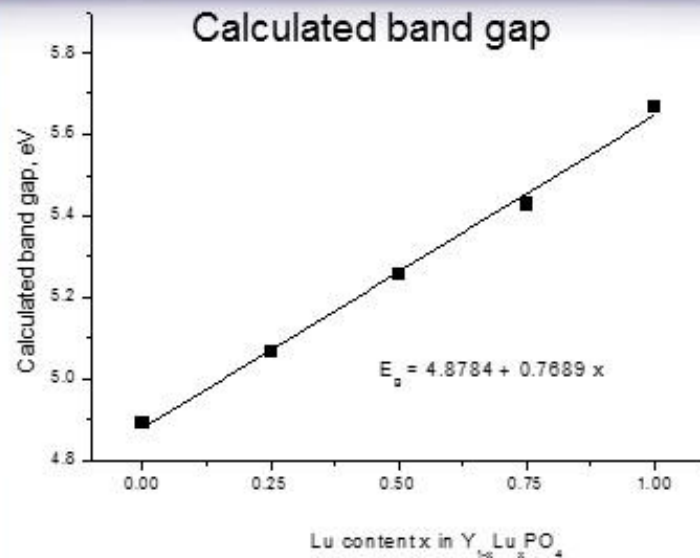
- the increase of depth of the trap



- the shift of the conduction band

# Bandgap

With increase of  $x$ :



- the shift of the peak to high temperature



- the the rise of depth of the trap

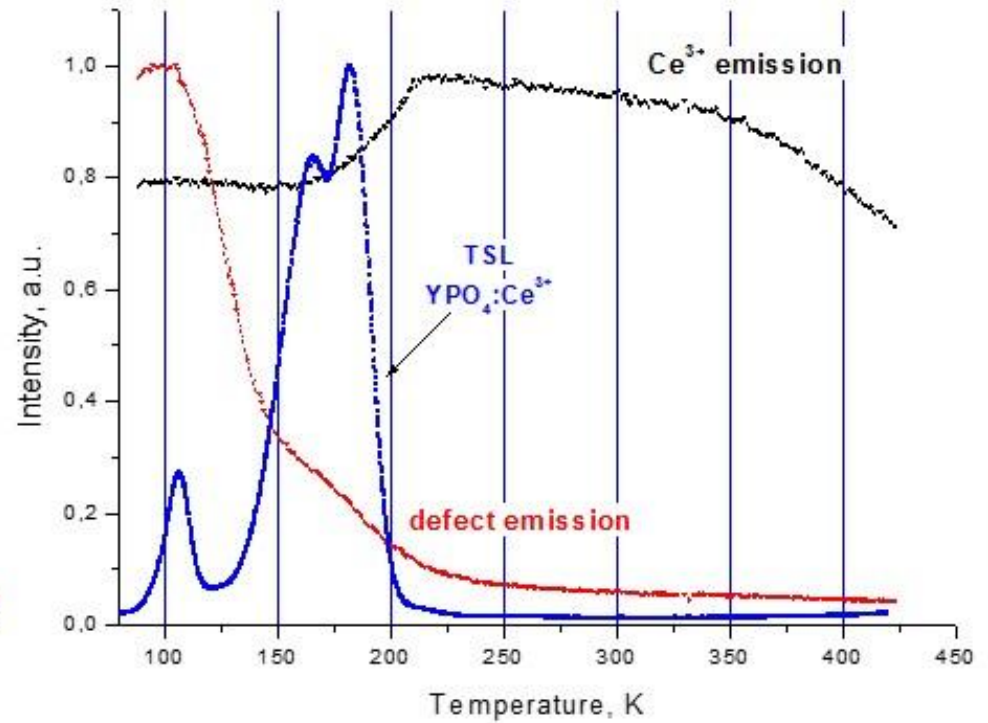
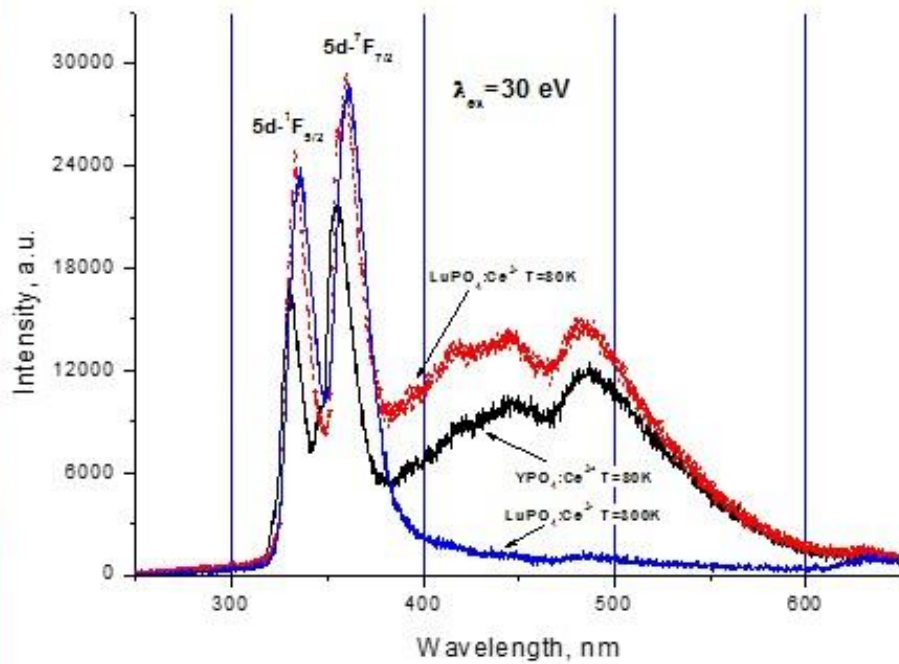


- the shift of the CB



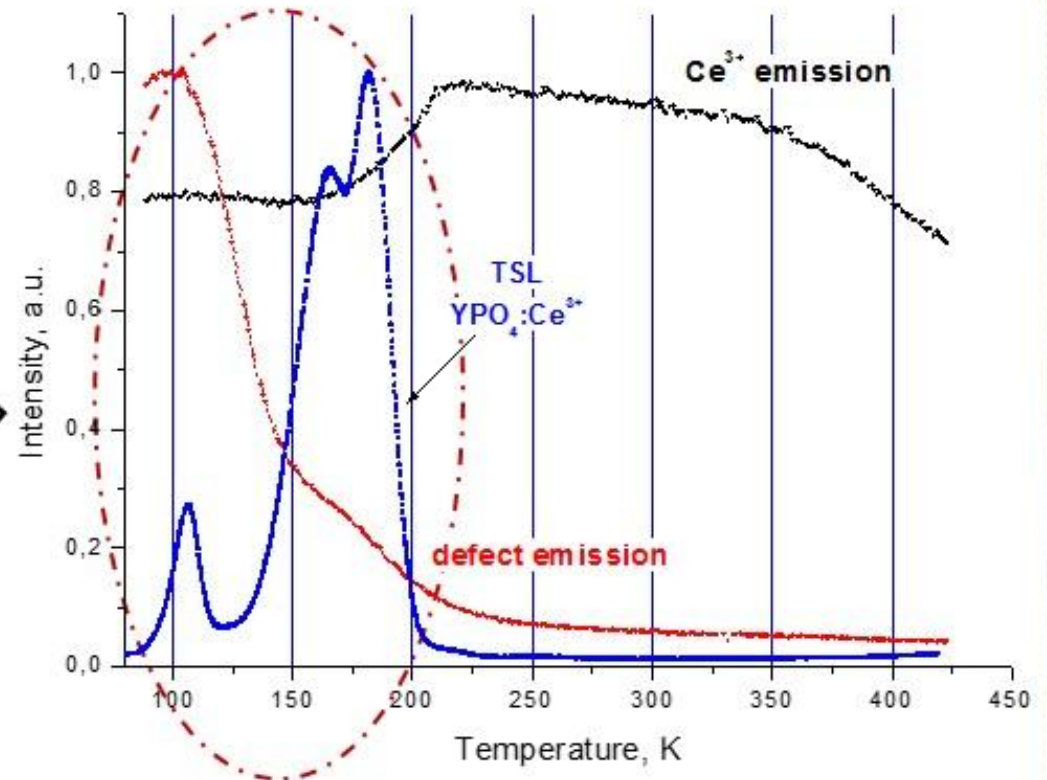
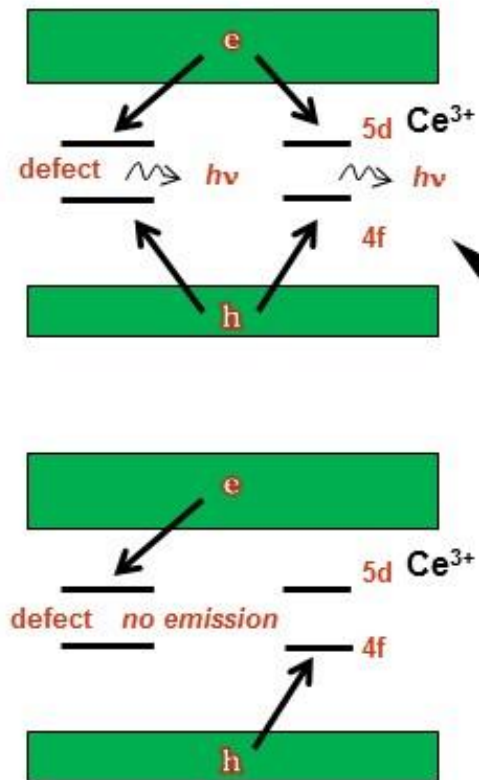
- the increase of bandgap

# Temperature dependence of luminescence



# Temperature dependence of luminescence

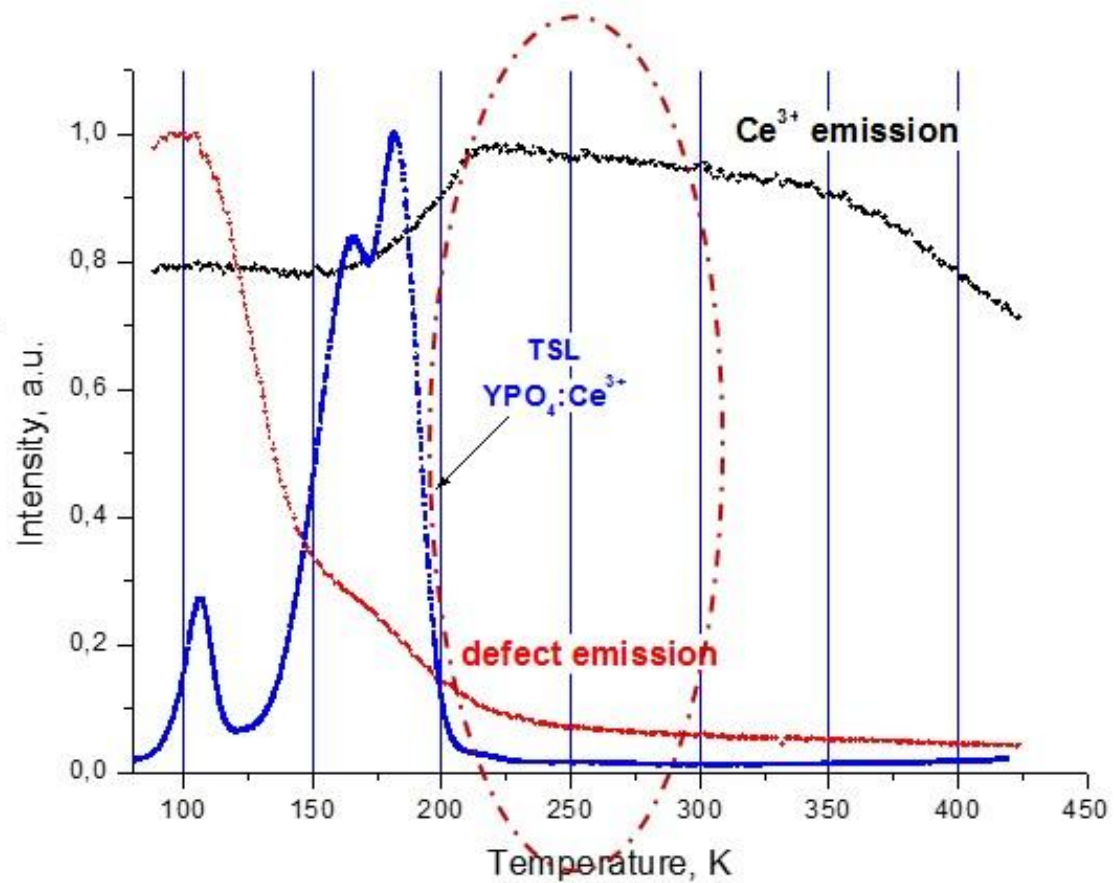
$T < 200 \text{ K}$ : the electron can be trapped by the defect



$\text{Ce}^{3+}$  emission reduces by 20 %

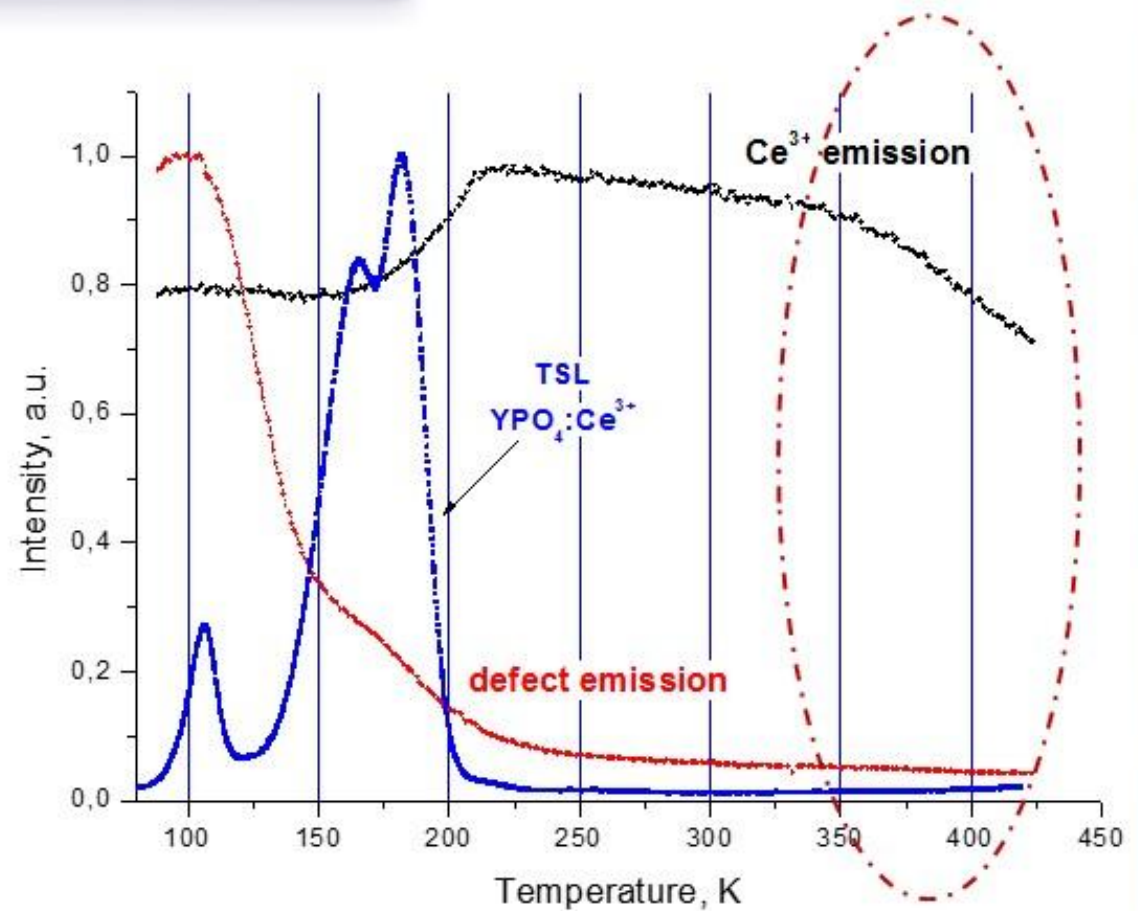
# Temperature dependence of luminescence

200 < T < 350 K:  
insignificant change of Ce<sup>3+</sup>  
emission



# Temperature dependence of luminescence

**T > 350 K:**  
temperature quenching of  
the  $\text{Ce}^{3+}$  emission



## Conclusions



- Luminescence properties of the set of phosphates solid solutions were investigated. The decrease of the emission intensity for intermediate values of  $x$  (opposite effect to the expected one) was detected .
- The luminescence excitation spectra have been analyzed. Time-resolved spectroscopy allowed to separate the slow processes of luminescence excitation connected with sequential capture of separated charge carriers on  $Ce^{3+}$  ion and the fast processes connected with the direct excitation of luminescence center.



## Conclusions



- The temperature dependence of both the  $\text{Ce}^{3+}$  and defect emission were studied. The competition between emission from  $\text{Ce}^{3+}$  ions and defect-related emission occurs at  $T < 200$  K and is attended by the trapping of electrons in vicinity of the defect-related states.
- The values of the bandgap were calculated. The calculations shows the increase of  $E_g$  and the result is further confirmed experimentally by the shift of the peaks of the TSL curves.



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Thank you for attention



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